Preferred Device

Triacs

Silicon Bidirectional Thyristors

Designed primarily for full-wave ac control applications, such as motor controls, heating controls or dimmers; or wherever full-wave, silicon gate-controlled devices are needed.

- High Commutating di/dt and High Immunity to dv/dt @ 125°C
- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- Blocking Voltage to 800 Volts
- On–State Current Rating of 16 Amperes RMS at 80°C
- High Surge Current Capability 150 Amperes
- Industry Standard TO-220AB Package for Ease of Design
- Glass Passivated Junctions for Reliability and Uniformity
- Device Marking: Logo, Device Type, e.g., MAC16HCD, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	V _{DRM,} V _{RRM}		Volts
MAC16HCD MAC16HCM MAC16HCN		400 600 800	
On–State RMS Current (Full Cycle Sine Wave 50 to 60 Hz; T _C = 80°C)	lT(RMS)	16	А
Peak Non-Repetitive Surge Current (One Full Cycle, 60 Hz, T _J = 125°C)	ITSM	150	А
Circuit Fusing Consideration ⁽²⁾ (t = 8.33 ms)	l ² t	93	A ² sec
Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 80°C)	Рдм	20	Watts
Average Gate Power (t = 8.3 ms, T _C = 80°C)	P _G (AV)	0.5	Watts
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

⁽¹⁾ VDRM and VRRM for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

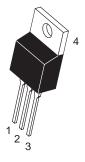


ON Semiconductor

http://onsemi.com

TRIACS 16 AMPERES RMS 400 thru 800 VOLTS





TO-220AB CASE 221A STYLE 4

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		
4	Main Terminal 2		

ORDERING INFORMATION

Device	Package	Shipping
MAC16HCD	TO220AB	50 Units/Rail
MAC16HCM	TO220AB	50 Units/Rail
MAC16HCN	TO220AB	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

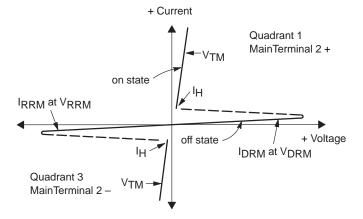
Characteristic	Symbol	Value	Unit
Thermal Resistance			°C/W
— Junction to Case — Junction to Ambient	R _{θJC} R _{θJA}	2.2 62.5	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				•
Peak Repetitive Blocking Current $T_J = 25^{\circ}C$ ($V_D = Rated V_{DRM}, V_{RRM}, Gate Open$) $T_J = 125^{\circ}C$	IDRM, IRRM		_ _	0.01 2.0	mA
ON CHARACTERISTICS					
Peak On–State Voltage ⁽¹⁾ (I _{TM} = ±21 A Peak)	VTM	_	-	1.6	Volts
Gate Trigger Current (Continuous dc) (V $_D$ = 12 V, R $_L$ = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	I _{GT}	10 10 10	16 18 22	50 50 50	mA
Holding Current ($V_D = 12 V$, Gate Open, Initiating Current = $\pm 150 \text{ mA}$)	lн	_	20	50	mA
Latch Current ($V_D = 12 \text{ V}, I_G = 50 \text{ mA}$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	IL.	 - -	33 36 33	60 80 60	mA
Gate Trigger Voltage (Continuous dc) (V $_{D}$ = 12 V, R $_{L}$ = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	VGT	0.5 0.5 0.5	0.80 0.73 0.82	1.5 1.5 1.5	Volts
DYNAMIC CHARACTERISTICS					
Rate of Change of Commutating Current (V _D = 400 V, ITM = 6A, Commutating dv/dt = 20 V/ μ s, CL = 10 μ F Gate Open, T _J = 125°C, f = 250 Hz, with Snubber) LL = 40 mH	(di/dt)c	15	_	_	A/ms
Critical Rate of Rise of Off–State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, Gate Open, T _J = 125°C)	dv/dt	750	_	_	V/µs
Repetitive Critical Rate of Rise of On-State Current IPK = 50 A; PW = 40 µsec; diG/dt = 200 mA/µsec; f = 60 Hz	di/dt	-	_	10	A/μs

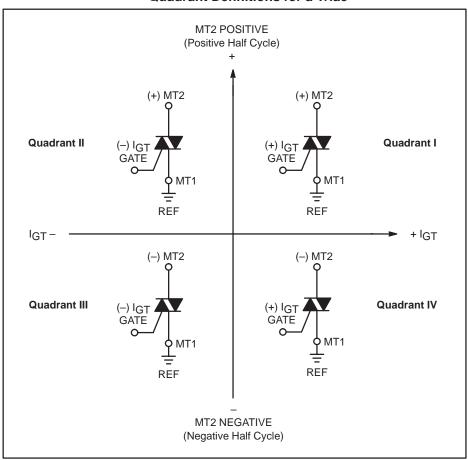
⁽¹⁾ Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V _{DRM}	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
lΗ	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

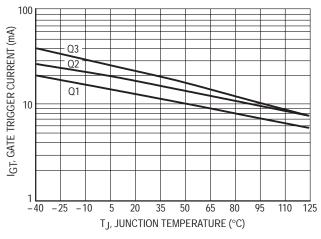


Figure 1. Typical Gate Trigger Current versus Junction Temperature

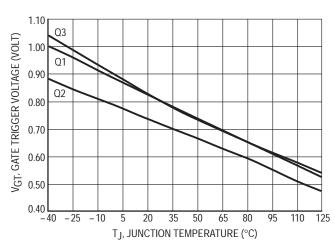


Figure 2. Typical Gate Trigger Voltage versus Junction Temperature

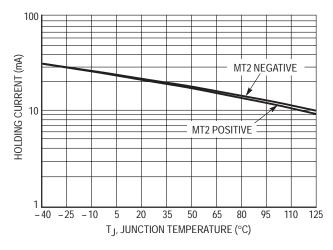


Figure 3. Typical Holding Current versus Junction Temperature

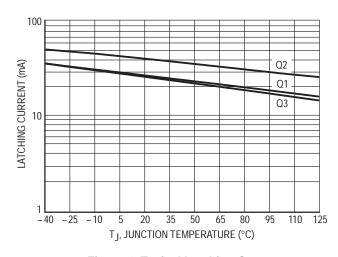


Figure 4. Typical Latching Current versus Junction Temperature

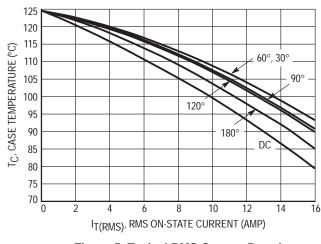


Figure 5. Typical RMS Current Derating

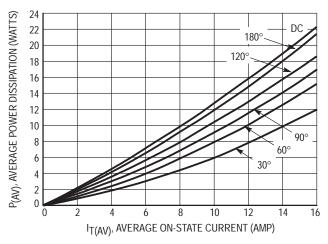


Figure 6. On-State Power Dissipation

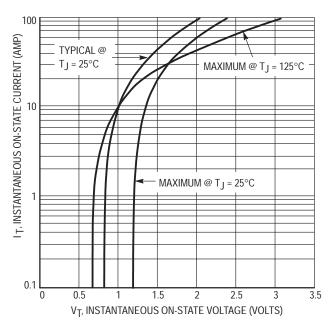


Figure 7. Typical On-State Characteristics

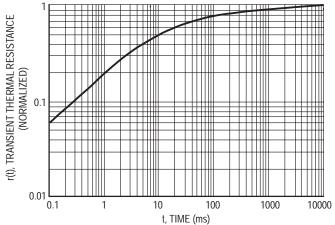
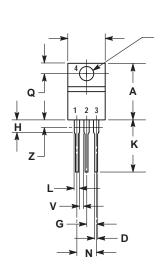
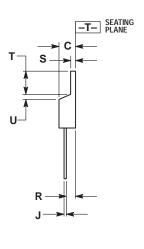


Figure 8. Typical Thermal Response

PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 **ISSUE Z**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INC	HES	MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 4:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. MAIN TERMINAL 2



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